NSN 5961-00-919-9191

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-919-9191 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 0.6 gate trigger voltage, dc and 1.5 on-state voltage, dc **Current Rating Per Characteristic:** 350.00 milliamperes forward current, total rms nanoamperes and 20.00 microamperes forward current, total rms preset **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0